RoHS

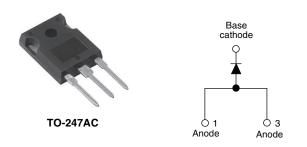
COMPLIANT

HALOGEN

FREE

**Vishay Semiconductors** 

## Hyperfast Rectifier, 60 A FRED Pt<sup>®</sup>



www.vishay.com

PRODUCT SUMMARY									
Package	TO-247AC								
I <sub>F(AV)</sub>	60 A								
V <sub>R</sub>	300 V								
V <sub>F</sub> at I <sub>F</sub>	0.85 V								
t <sub>rr</sub> typ.	28 ns								
T <sub>J</sub> max.	175 °C								
Diode variation	Single die								

#### **FEATURES**

- Hyperfast recovery time
- · Low forward voltage drop
- Low leakage current
- · Soft recovery device
- 175 °C operating junction temperature
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **DESCRIPTION / APPLICATIONS**

VS-60APH03-N3 series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for PDP and use in the output rectification stage for SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Cathode to anode voltage	V <sub>R</sub>		300	V						
Continuous forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 103 °C	60	А						
Single pulse forward current	I <sub>FSM</sub>	$T_J = 25 \ ^\circ C$ , 10 ms sine pulse	450							
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	300	-	-					
Forward voltage		I <sub>F</sub> = 30 A	-	1.0	1.25					
	V <sub>F</sub>	I <sub>F</sub> = 60 A	-	-	1.45	V				
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	0.85	1.10	1				
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	-	1.30					
Deverae leekege eurrent	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	10					
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	100	μA				
Junction capacitance	CT	V <sub>R</sub> = 300 V	-	70	-	pF				
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	3.5	-	nH				

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### **Vishay Semiconductors**

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 10$	00 A/µs, V <sub>R</sub> = 30 V	-	28	-				
	+	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50$	-	34	-	ns				
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	42	-	115			
		T <sub>J</sub> = 125 °C		-	64	-				
Deals recovery ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	l <sub>F</sub> = 60 A dl⊧/dt = 200 A/µs	- 3.0	-	•				
Peak recovery current		T <sub>J</sub> = 125 °C	$V_{\rm R} = 200 \text{ A/}\mu\text{s}$	-	8.5	-	A			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	65	-	nC			
		T <sub>J</sub> = 125 °C		-	273	-				

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C				
Thermal resistance, junction to case	R <sub>thJC</sub>		-	0.56	0.80	°C/W				
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	C/VV				
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.4	-					
Approvimeto Weight			-	6.0	-	g				
Approximate Weight			-	0.22	-	oz.				
Mounting torque			6.0	-	12	kgf. cm				
Mounting torque			(12)	-	(10)	(lbf.in)				
Marking device		Case style TO-247AC		60AI	PH03	•				

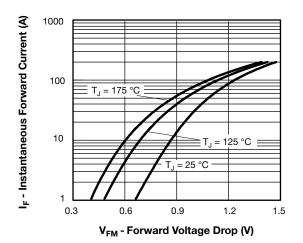


Fig. 1 - Typical Forward Voltage Drop Characteristics

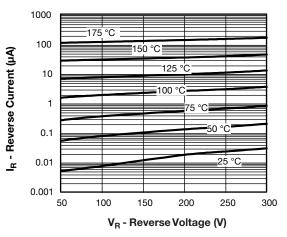


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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## **VS-60APH03-N3**

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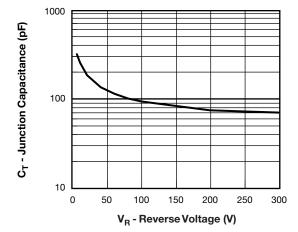


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

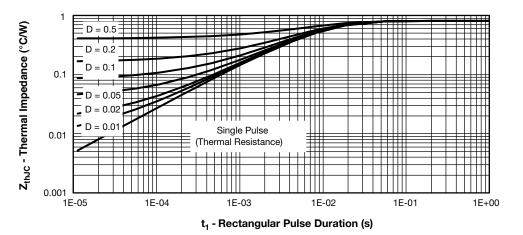
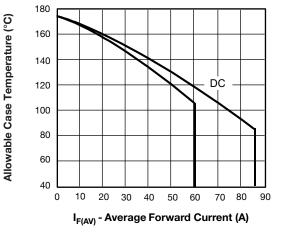
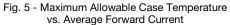


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics





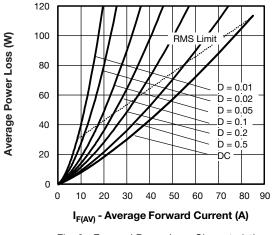


Fig. 6 - Forward Power Loss Characteristics

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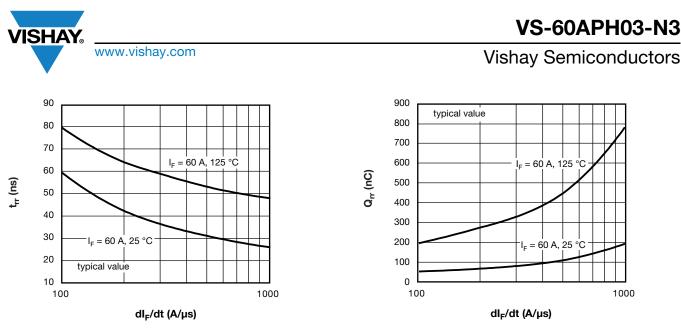


Fig. 7 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

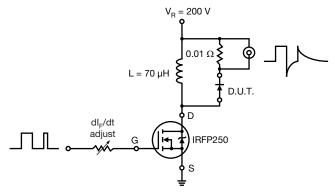
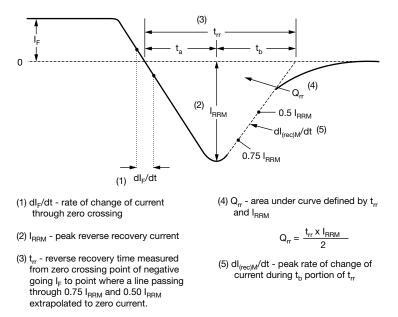
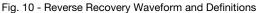


Fig. 9 - Reverse Recovery Parameter Test Circuit





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#### **ORDERING INFORMATION TABLE**

Device code	vs-	60	А	Р	н	03	-N3
		2	3	4	5	6	7
	1 -		-	niconduc		oduct	
	2 - 3 -	Circ	uit conf	ng (60 = iguratior	,		
	4 -		single c TO-247				
	5 - 6 -			ast rectifi de (03 =			
	7 -	N3	= haloge	en-free,	RoHS-c	complia	nt, and

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-60APH03-N3	25	500	Antistatic plastic tube						

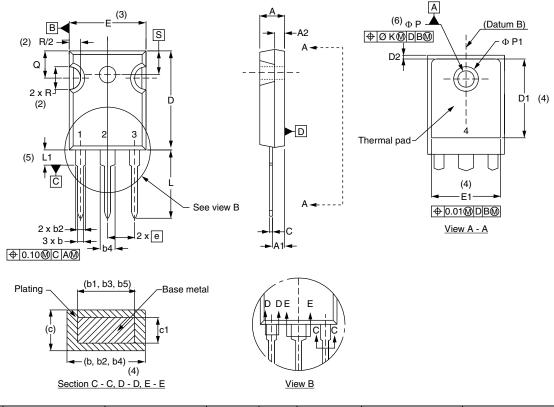
LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?95542							
Part marking information	www.vishay.com/doc?95007							
SPICE model	www.vishay.com/doc?96075							





TO-247AC - 50 mils L/F

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTEO	SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			e	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0	)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØР	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	5.51	BSC	0.217	BSC	
D1	13.08	-	0.515	-	4							

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(4)</sup> Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

<sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension c and Q

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